

Description

The CXK79M72C161GB (organized as 262,144 words by 72 bits), CXK79M36C161GB (organized as 524,288 words by 36 bits), and the CXK79M18C161GB (organized as 1,048,576 words by 18 bits) are high speed CMOS synchronous static RAMs with common I/O pins. They are manufactured in compliance with the JEDEC-standard 209 pin BGA package pinouts defined for SigmaRAMs. They integrate input registers, high speed RAM, output registers, and a two-deep write buffer onto a single monolithic IC. Single Data Rate (SDR) Pipelined (PL) read operations and Late Write (LW) write operations are supported, providing a high-performance user interface. Positive and negative output clocks are provided for applications requiring source-synchronous operation.

All address and control input signals are registered on the rising edge of the CK input clock.

During read operations, output data is driven valid once, from the rising edge of CK, one full cycle after the address and control signals are registered.

During write operations, input data is registered once, on the rising edge of CK, one full cycle after the address and control signals are registered.

Output drivers are series-terminated, and output impedance is selectable via the ZQ control pin. When ZQ is tied “low”, the impedance of the SRAM’s output drivers is set to $\sim 25\Omega$. When ZQ is tied “high” or left unconnected, the impedance of the SRAM’s output drivers is set to $\sim 50\Omega$.

300 MHz operation (300 Mbps) is obtained from a single 1.8V power supply. JTAG boundary scan interface is provided using a subset of IEEE standard 1149.1 protocol.

Features

- | <u>3 Speed Bins</u> | <u>Cycle Time / Data Access Time</u> |
|---------------------|--------------------------------------|
| -33 | 3.3ns / 1.8ns |
| -4 | 4.0ns / 2.1ns |
| -5 | 5.0ns / 2.3ns |
- Single 1.8V power supply (V_{DD}): 1.7V (min) to 1.95V (max)
- Dedicated output supply voltage (V_{DDQ}): 1.4V (min) to V_{DD} (max)
- LVCMOS-compatible I/O interface
- Common I/O
- Single Data Rate (SDR) data transfers
- Pipelined (PL) read operations
- Late Write (LW) write operations
- Burst capability with internally controlled Linear Burst address sequencing
- Burst length of two, three, or four, with automatic address wrap
- Full read/write data coherency
- Byte write capability
- Single-ended input clock (CK)
- Data-referenced output clocks ($CQ1$, $\overline{CQ1}$, $CQ2$, $\overline{CQ2}$)
- Selectable output driver impedance via dedicated control pin (ZQ)
- Depth expansion capability (2 or 4 banks) via programmable chip enables (E2, E3, EP2, EP3)
- JTAG boundary scan (subset of IEEE standard 1149.1)
- 209 pin (11x19), 1mm pitch, 14mm x 22mm Ball Grid Array (BGA) package

256Kb x 72 Pin Assignment (Top View)

| | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 10 | 11 |
|---|-----|------------------|------------------|------------------|-----------------|-----------------|-----------------|------------------|------------------|------------------|-----|
| A | DQg | DQg | A | E2 | A | ADV | A | E3 | A | DQb | DQb |
| B | DQg | DQg | \overline{Bc} | \overline{Bg} | NC (x36) | \overline{W} | A | \overline{Bb} | \overline{Bf} | DQb | DQb |
| C | DQg | DQg | \overline{Bh} | \overline{Bd} | NC (144M) | $\overline{E1}$ | NC (x18) | \overline{Be} | \overline{Ba} | DQb | DQb |
| D | DQg | DQg | V _{SS} | NC | NC | MCL | NC | NC | V _{SS} | DQb | DQb |
| E | DQg | DQc | V _{DDQ} | V _{DDQ} | V _{DD} | V _{DD} | V _{DD} | V _{DDQ} | V _{DDQ} | DQf | DQb |
| F | DQc | DQc | V _{SS} | V _{SS} | V _{SS} | ZQ | V _{SS} | V _{SS} | V _{SS} | DQf | DQf |
| G | DQc | DQc | V _{DDQ} | V _{DDQ} | V _{DD} | EP2 | V _{DD} | V _{DDQ} | V _{DDQ} | DQf | DQf |
| H | DQc | DQc | V _{SS} | V _{SS} | V _{SS} | EP3 | V _{SS} | V _{SS} | V _{SS} | DQf | DQf |
| J | DQc | DQc | V _{DDQ} | V _{DDQ} | V _{DD} | MCL | V _{DD} | V _{DDQ} | V _{DDQ} | DQf | DQf |
| K | CQ2 | $\overline{CQ2}$ | CK | NC | V _{SS} | MCL | V _{SS} | NC | NC | $\overline{CQ1}$ | CQ1 |
| L | DQh | DQh | V _{DDQ} | V _{DDQ} | V _{DD} | MCH | V _{DD} | V _{DDQ} | V _{DDQ} | DQa | DQa |
| M | DQh | DQh | V _{SS} | V _{SS} | V _{SS} | MCH | V _{SS} | V _{SS} | V _{SS} | DQa | DQa |
| N | DQh | DQh | V _{DDQ} | V _{DDQ} | V _{DD} | MCH | V _{DD} | V _{DDQ} | V _{DDQ} | DQa | DQa |
| P | DQh | DQh | V _{SS} | V _{SS} | V _{SS} | MCL | V _{SS} | V _{SS} | V _{SS} | DQa | DQa |
| R | DQd | DQh | V _{DDQ} | V _{DDQ} | V _{DD} | V _{DD} | V _{DD} | V _{DDQ} | V _{DDQ} | DQa | DQe |
| T | DQd | DQd | V _{SS} | NC | NC | MCL | NC | NC | V _{SS} | DQe | DQe |
| U | DQd | DQd | NC | A | NC (72M) | A | NC (36M) | A | NC | DQe | DQe |
| V | DQd | DQd | A | A | A | A1 | A | A | A | DQe | DQe |
| W | DQd | DQd | TMS | TDI | A | A0 | A | TDO | TCK | DQe | DQe |

512Kb x 36 Pin Assignment (Top View)

| | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 10 | 11 |
|---|-----|------------------|------------------|------------------|-----------------|-----------------|-----------------|------------------|------------------|------------------|-----|
| A | NC | NC | A | E2 | A | ADV | A | E3 | A | DQb | DQb |
| B | NC | NC | \overline{Bc} | NC | A (x36) | \overline{W} | A | \overline{Bb} | NC | DQb | DQb |
| C | NC | NC | NC | \overline{Bd} | NC (144M) | $\overline{E1}$ | NC (x18) | NC | \overline{Ba} | DQb | DQb |
| D | NC | NC | V _{SS} | NC | NC | MCL | NC | NC | V _{SS} | DQb | DQb |
| E | NC | DQc | V _{DDQ} | V _{DDQ} | V _{DD} | V _{DD} | V _{DD} | V _{DDQ} | V _{DDQ} | NC | DQb |
| F | DQc | DQc | V _{SS} | V _{SS} | V _{SS} | ZQ | V _{SS} | V _{SS} | V _{SS} | NC | NC |
| G | DQc | DQc | V _{DDQ} | V _{DDQ} | V _{DD} | EP2 | V _{DD} | V _{DDQ} | V _{DDQ} | NC | NC |
| H | DQc | DQc | V _{SS} | V _{SS} | V _{SS} | EP3 | V _{SS} | V _{SS} | V _{SS} | NC | NC |
| J | DQc | DQc | V _{DDQ} | V _{DDQ} | V _{DD} | MCL | V _{DD} | V _{DDQ} | V _{DDQ} | NC | NC |
| K | CQ2 | $\overline{CQ2}$ | CK | NC | V _{SS} | MCL | V _{SS} | NC | NC | $\overline{CQ1}$ | CQ1 |
| L | NC | NC | V _{DDQ} | V _{DDQ} | V _{DD} | MCH | V _{DD} | V _{DDQ} | V _{DDQ} | DQa | DQa |
| M | NC | NC | V _{SS} | V _{SS} | V _{SS} | MCH | V _{SS} | V _{SS} | V _{SS} | DQa | DQa |
| N | NC | NC | V _{DDQ} | V _{DDQ} | V _{DD} | MCH | V _{DD} | V _{DDQ} | V _{DDQ} | DQa | DQa |
| P | NC | NC | V _{SS} | V _{SS} | V _{SS} | MCL | V _{SS} | V _{SS} | V _{SS} | DQa | DQa |
| R | DQd | NC | V _{DDQ} | V _{DDQ} | V _{DD} | V _{DD} | V _{DD} | V _{DDQ} | V _{DDQ} | DQa | NC |
| T | DQd | DQd | V _{SS} | NC | NC | MCL | NC | NC | V _{SS} | NC | NC |
| U | DQd | DQd | NC | A | NC (72M) | A | NC (36M) | A | NC | NC | NC |
| V | DQd | DQd | A | A | A | A1 | A | A | A | NC | NC |
| W | DQd | DQd | TMS | TDI | A | A0 | A | TDO | TCK | NC | NC |

1Mb x 18 Pin Assignment (Top View)

| | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 10 | 11 |
|---|-----|------------------|------------------|------------------|-----------------|-----------------|-----------------|------------------|------------------|------------------|-----|
| A | NC | NC | A | E2 | A | ADV | A | E3 | A | NC | NC |
| B | NC | NC | \overline{Bb} | NC | A (x36) | \overline{W} | A | NC | NC | NC | NC |
| C | NC | NC | NC | NC | NC (144M) | \overline{EI} | A (x18) | NC | \overline{Ba} | NC | NC |
| D | NC | NC | V _{SS} | NC | NC | MCL | NC | NC | V _{SS} | NC | NC |
| E | NC | DQb | V _{DDQ} | V _{DDQ} | V _{DD} | V _{DD} | V _{DD} | V _{DDQ} | V _{DDQ} | NC | NC |
| F | DQb | DQb | V _{SS} | V _{SS} | V _{SS} | ZQ | V _{SS} | V _{SS} | V _{SS} | NC | NC |
| G | DQb | DQb | V _{DDQ} | V _{DDQ} | V _{DD} | EP2 | V _{DD} | V _{DDQ} | V _{DDQ} | NC | NC |
| H | DQb | DQb | V _{SS} | V _{SS} | V _{SS} | EP3 | V _{SS} | V _{SS} | V _{SS} | NC | NC |
| J | DQb | DQb | V _{DDQ} | V _{DDQ} | V _{DD} | MCL | V _{DD} | V _{DDQ} | V _{DDQ} | NC | NC |
| K | CQ2 | $\overline{CQ2}$ | CK | NC | V _{SS} | MCL | V _{SS} | NC | NC | $\overline{CQ1}$ | CQ1 |
| L | NC | NC | V _{DDQ} | V _{DDQ} | V _{DD} | MCH | V _{DD} | V _{DDQ} | V _{DDQ} | DQa | DQa |
| M | NC | NC | V _{SS} | V _{SS} | V _{SS} | MCH | V _{SS} | V _{SS} | V _{SS} | DQa | DQa |
| N | NC | NC | V _{DDQ} | V _{DDQ} | V _{DD} | MCH | V _{DD} | V _{DDQ} | V _{DDQ} | DQa | DQa |
| P | NC | NC | V _{SS} | V _{SS} | V _{SS} | MCL | V _{SS} | V _{SS} | V _{SS} | DQa | DQa |
| R | NC | NC | V _{DDQ} | V _{DDQ} | V _{DD} | V _{DD} | V _{DD} | V _{DDQ} | V _{DDQ} | DQa | NC |
| T | NC | NC | V _{SS} | NC | NC | MCL | NC | NC | V _{SS} | NC | NC |
| U | NC | NC | NC | A | NC (72M) | A | NC (36M) | A | NC | NC | NC |
| V | NC | NC | A | A | A | A1 | A | A | A | NC | NC |
| W | NC | NC | TMS | TDI | A | A0 | A | TDO | TCK | NC | NC |

Pin Description

| Symbol | Type | Quantity | Description |
|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------|----------------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| A | Input | x72 = 16 x36 = 17 x18 = 18 | Address Inputs - Registered on the rising edge of CK. |
| A1, A0 | Input | 2 | Address Inputs 1,0 - Registered on the rising edge of CK. Initialize burst counter. |
| DQa, DQb DQc, DQd DQe, DQf DQg, DQh | I/O | x72 = 72 x36 = 36 x18 = 18 | Data Inputs / Outputs - Registered on the rising edge of CK during write operations. Driven from the rising edge of CK during read operations. DQa - indicates Data Byte a DQb - indicates Data Byte b DQc - indicates Data Byte c DQd - indicates Data Byte d DQe - indicates Data Byte e DQf - indicates Data Byte f DQg - indicates Data Byte g DQh - indicates Data Byte h |
| CK | Input | 1 | Input Clock |
| CQ1, $\overline{\text{CQ1}}$ CQ2, $\overline{\text{CQ2}}$ | Output | 4 | Output Clocks |
| $\overline{\text{EI}}$ | Input | 1 | Chip Enable Control Input - Registered on the rising edge of CK. $\overline{\text{EI}} = 0$ enables the device to accept read and write commands. $\overline{\text{EI}} = 1$ disables the device. See the Clock Truth Table section for further information. |
| E2, E3 | Input | 2 | Programmable Chip Enable Control Inputs - Registered on the rising edge of CK. See the Clock Truth Table and Depth Expansion sections for further information. |
| EP2, EP3 | Input | 2 | Programmable Chip Enable Active-Level Select Inputs - These pins must be tied “high” or “low” at power-up. See the Clock Truth Table and Depth Expansion sections for further information. |
| ADV | Input | 1 | Address Advance Control Input - Registered on the rising edge of CK. ADV = 0 loads a new address and begins a new operation when the device is enabled. ADV = 1 increments the address and continues the previous operation when the device is enabled. See the Clock Truth Table section for further information. |
| $\overline{\text{W}}$ | Input | 1 | Write Enable Control Input - Registered on the rising edge of CK. $\overline{\text{W}} = 0$ specifies a write operation when ADV = 0 and the device is enabled. $\overline{\text{W}} = 1$ specifies a read operation when ADV = 0 and the device is enabled. See the Clock Truth Table section for further information. |
| $\overline{\text{Ba}}, \overline{\text{Bb}}, \overline{\text{Bc}}$ $\overline{\text{Bd}}, \overline{\text{Be}}, \overline{\text{Bf}}$ $\overline{\text{Bg}}, \overline{\text{Bh}}$ | Input | x72 = 8 x36 = 4 x18 = 2 | Byte Write Enable Control Inputs - Registered on the rising edge of CK. $\overline{\text{Ba}} = 0$ specifies write Data Byte a during a write operation $\overline{\text{Bb}} = 0$ specifies write Data Byte b during a write operation $\overline{\text{Bc}} = 0$ specifies write Data Byte c during a write operation $\overline{\text{Bd}} = 0$ specifies write Data Byte d during a write operation $\overline{\text{Be}} = 0$ specifies write Data Byte e during a write operation $\overline{\text{Bf}} = 0$ specifies write Data Byte f during a write operation $\overline{\text{Bg}} = 0$ specifies write Data Byte g during a write operation $\overline{\text{Bh}} = 0$ specifies write Data Byte h during a write operation See the Clock Truth Table section for further information. |
| ZQ | Input | 1 | Output Impedance Control Input - This pin must be tied “high” or “low” at power-up. ZQ = 0 selects ~25Ω output impedance ZQ = 1 selects ~50Ω output impedance Note: This pin can also be left unconnected. It is weakly pulled “high” internally. |

| Symbol | Type | Quantity | Description |
|------------------|---------|----------------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| V _{DD} | | 14 | 1.8V Core Power Supply - Core supply voltage. |
| V _{DDQ} | | 24 | Output Power Supply - Output buffer supply voltage. |
| V _{SS} | | 30 | Ground |
| TCK | Input | 1 | JTAG Clock |
| TMS | Input | 1 | JTAG Mode Select - Weakly pulled “high” internally. |
| TDI | Input | 1 | JTAG Data In - Weakly pulled “high” internally. |
| TDO | Output | 1 | JTAG Data Out |
| MCL | *Input* | 5 | Must Connect “Low” - May not be actual input pins. |
| MCH | *Input* | 3 | Must Connect “High” - May not be actual input pins. |
| NC | | x72 = 18 x36 = 57 x18 = 76 | No Connect - These pins are true no-connects, i.e. there is no internal chip connection to these pins. They can be left unconnected or tied directly to V _{DD} , V _{DDQ} , or V _{SS} . |

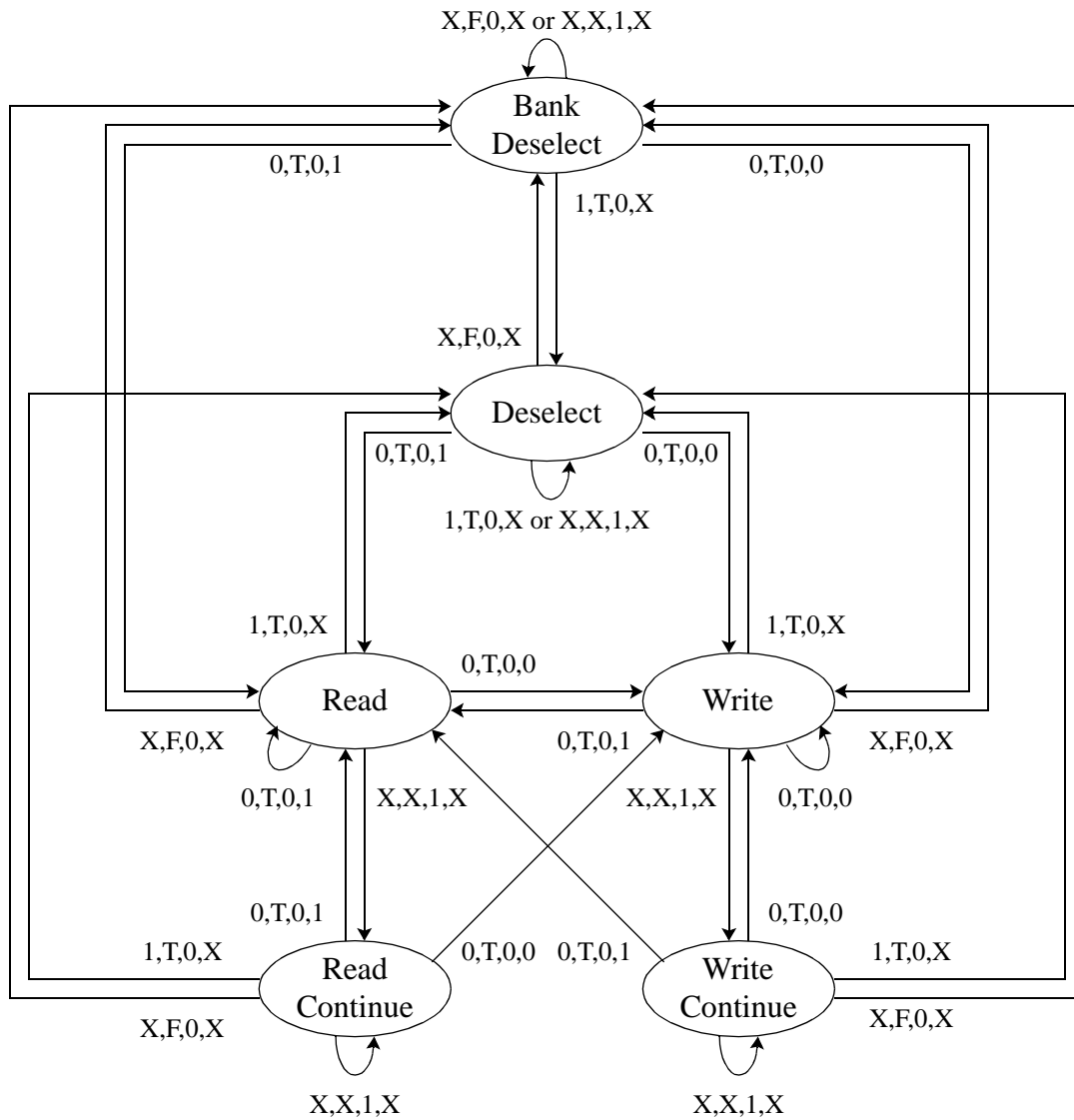
Clock Truth Table

| CK | $\overline{E1}$ (t_n) | E (t_n) | ADV (t_n) | \overline{W} (t_n) | B (t_n) | Previous Operation | Current Operation | DQ/CQ (t_n) | DQ/CQ (t_{n+1}) |
|----|------------------------------|----------------|------------------|-----------------------------|----------------|-----------------------|--------------------------------------------------------------------------------|--------------------|------------------------|
| ↑ | X | F | 0 | X | X | X | Bank Deselect | *** | Hi-Z |
| ↑ | X | X | 1 | X | X | Bank Deselect | Bank Deselect (Continue) | Hi-Z | Hi-Z |
| ↑ | 1 | T | 0 | X | X | X | Deselect | *** | Hi-Z/CQ |
| ↑ | X | X | 1 | X | X | Deselect | Deselect (Continue) | Hi-Z/CQ | Hi-Z/CQ |
| ↑ | 0 | T | 0 | 0 | T | X | Write Loads new address Stores DQx if Bx = 0 | *** | D1/CQ |
| ↑ | 0 | T | 0 | 0 | F | X | Write (Abort) Loads new address No data stored | *** | X/CQ |
| ↑ | X | X | 1 | X | T | Write | Write Continue Increments address by 1 Stores DQx if $\overline{Bx} = 0$ | D1/CQ | D2/CQ |
| ↑ | X | X | 1 | X | F | Write | Write Continue (Abort) Increments address by 1 No data stored | D1/CQ | X/CQ |
| ↑ | 0 | T | 0 | 1 | X | X | Read Loads new address | *** | Q1/CQ |
| ↑ | X | X | 1 | X | X | Read | Read Continue Increments address by 1 | Q1/CQ | Q2/CQ |

Notes:

1. “1” = input “high”; “0” = input “low”; “X” = input “don’t care”; “T” = input “true”; “F” = input “false”.
2. “***” indicates that the DQ input requirement or output state and the CQ output state are determined by the previous operation.
3. If $E2 = EP2$ and $E3 = EP3$ then $E = “T”$ else $E = “F”$.
4. If one or more $\overline{Bx} = 0$ then $B = “T”$ else $B = “F”$.
5. DQs are tri-stated in response to Bank Deselect, Deselect, and Write commands, one full cycle after the command is sampled.
6. CQs are tri-stated in response to Bank Deselect commands only, one full cycle after the command is sampled.
7. Up to three (3) Continue operations may be initiated after a Read or Write operation is initiated to burst transfer up to four (4) distinct pieces of data per single external address input. If a fourth (4th) Continue operation is initiated, the internal address wraps back to the initial external (base) address.

State Diagram



Notes:

1. The notation "X,X,X,X" controlling the state transitions above indicate the states of inputs $\overline{E1}$, E, ADV, and \overline{W} respectively.
2. "1" = input "high"; "0" = input "low"; "X" = input "don't care"; "T" = input "true"; "F" = input "false".
3. If $E2 = EP2$ and $E3 = EP3$ then $E = "T"$ else $E = "F"$.

•Burst (Continue) Operations

Burst operations follow the **Linear Burst** address sequence depicted in the table below:

| | A(1:0) | | | | Sequence Key |
|--------------------|--------|----|----|----|-----------------------------------------------------|
| 1st (Base) Address | 00 | 01 | 10 | 11 | A1, A0 |
| 2nd Address | 01 | 10 | 11 | 00 | (A1 xor A0), $\overline{A0}$ |
| 3rd Address | 10 | 11 | 00 | 01 | $\overline{A1}$, A0 |
| 4th Address | 11 | 00 | 01 | 10 | $\overline{(A1 \text{ xor } A0)}$, $\overline{A0}$ |

Up to three (3) Continue operations may be initiated after a Read or Write operation is initiated to burst transfer up to four (4) distinct pieces of data per single external address input. If a fourth (4th) Continue operation is initiated, the internal address wraps back to the initial external (base) address.

•Depth Expansion

Depth expansion in these devices is supported via programmable chip enables E2 and E3. The active levels of E2 and E3 are programmable through the static inputs EP2 and EP3 respectively. When EP2 is tied “high”, E2 functions as an active-high input. When EP2 is tied “low”, E2 functions as an active-low input. Similarly, when EP3 is tied “high”, E3 functions as an active-high input. And, when EP3 is tied “low”, E3 functions as an active-low input.

The programmability of E2 and E3 allows four banks of depth expansion to be accomplished with no additional logic. By programming E2 and E3 of four devices in a binary sequence (00, 01, 10, 11), and by driving E2 and E3 with external address signals, the four devices can be made to look like one larger device.

When these devices are deselected via chip enable $\overline{E1}$, the output clocks continue to toggle. However, when these devices are deselected via programmable chip enables E2 or E3, the output clocks are forced to a Hi-Z state. See the Clock Truth Table for further information.

•Output Driver Impedance Control

The impedance of the data and clock output drivers in these devices can be controlled via the static input ZQ. When ZQ is tied “low”, output driver impedance is set to $\sim 25\Omega$. When ZQ is tied “high” or left unconnected, output driver impedance is set to $\sim 50\Omega$. See the DC Electrical Characteristics section for further information.

•Power-Up Sequence

For reliability purposes, Sony recommends that power supplies power up in the following sequence: V_{SS} , V_{DD} , V_{DDQ} , and Inputs. V_{DDQ} should never exceed V_{DD} . If this power supply sequence cannot be met, a large bypass diode may be required between V_{DD} and V_{DDQ} . Please contact Sony Memory Application Department for further information.

•Absolute Maximum Ratings

| Parameter | Symbol | Rating | Units |
|-----------------------------------------------|-----------|----------------------------------|-------|
| Supply Voltage | V_{DD} | -0.5 to +2.5 | V |
| Output Supply Voltage | V_{DDQ} | -0.5 to +2.3 | V |
| Input Voltage (Address, Control, Data, Clock) | V_{IN} | -0.5 to $V_{DDQ}+0.5$ (2.3V max) | V |
| Input Voltage (EP2, EP3, MCL, MCH, ZQ) | V_{MIN} | -0.5 to $V_{DD}+0.5$ (2.5V max) | V |
| Input Voltage (TCK, TMS, TDI) | V_{TIN} | -0.5 to $V_{DD}+0.5$ (2.5V max) | V |
| Operating Temperature | T_A | 0 to 85 | °C |
| Junction Temperature | T_J | 0 to 110 | °C |
| Storage Temperature | T_{STG} | -55 to 150 | °C |

Note: Stresses greater than those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. This is a stress rating only, and functional operation of the device at these or any other conditions other than those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

•BGA Package Thermal Characteristics

| Parameter | Symbol | Rating | Units |
|------------------------------|---------------|--------|-------|
| Junction to Case Temperature | Θ_{JC} | 3.6 | °C/W |

•I/O Capacitance

($T_A = 25^\circ\text{C}$, $f = 1\text{ MHz}$)

| Parameter | | Symbol | Test conditions | Min | Max | Units |
|--------------------|----------|-----------|-----------------|-----|-----|-------|
| Input Capacitance | Address | C_{IN} | $V_{IN} = 0V$ | --- | 3.5 | pF |
| | Control | C_{IN} | $V_{IN} = 0V$ | --- | 3.5 | pF |
| | CK Clock | C_{KIN} | $V_{KIN} = 0V$ | --- | 4.0 | pF |
| Output Capacitance | Data | C_{OUT} | $V_{OUT} = 0V$ | --- | 4.5 | pF |
| | CQ Clock | C_{OUT} | $V_{OUT} = 0V$ | --- | 4.5 | pF |

Note: These parameters are sampled and are not 100% tested.

•DC Recommended Operating Conditions

 (V_{SS} = 0V, T_A = 0 to 85°C)

| Parameter | Symbol | Min | Typ | Max | Units | Notes |
|-------------------------------------------------------|------------------|---------------------------|-----|---------------------------|-------|-------|
| Supply Voltage | V _{DD} | 1.7 | 1.8 | 1.95 | V | |
| Output Supply Voltage | V _{DDQ} | 1.4 | --- | V _{DD} | V | |
| Input High Voltage (Address, Control, Data, Clock) | V _{IH} | V _{DDQ} /2 + 0.3 | --- | V _{DDQ} + 0.3 | V | 1 |
| Input Low Voltage (Address, Control, Data, Clock) | V _{IL} | -0.3 | --- | V _{DDQ} /2 - 0.3 | V | 2 |
| Input High Voltage (EP2, EP3, MCH, ZQ) | V _{MIH} | V _{DDQ} /2 + 0.4 | --- | V _{DD} + 0.3 | V | |
| Input Low Voltage (EP2, EP3, MCL, ZQ) | V _{MIL} | -0.3 | --- | V _{DDQ} /2 - 0.4 | V | |

1. V_{IH} (max) AC = V_{DDQ} + 0.9V for pulse widths less than one-quarter of the cycle time (t_{CYC}/4).
2. V_{IL} (min) AC = -0.9V for pulse widths less than one-quarter of the cycle time (t_{CYC}/4).

•DC Electrical Characteristics
($V_{DD} = 1.8V \pm 0.1V$, $V_{SS} = 0V$, $T_A = 0$ to $85^\circ C$)

| Parameter | Symbol | Test Conditions | Min | Typ | Max | Units | Notes |
|-------------------------------------------------|-------------|---------------------------------------------------|-----------------|-----|-----|----------|-------|
| Input Leakage Current (Address, Control, Clock) | I_{LI} | $V_{IN} = V_{SS}$ to V_{DDQ} | -5 | --- | 5 | uA | |
| Input Leakage Current (EP2, EP3) | I_{MLI1} | $V_{MIN} = V_{SS}$ to V_{DD} | -10 | --- | 10 | uA | |
| Input Leakage Current (MCH) | I_{MLI2} | $V_{MIN} = V_{MIH}$ (min) to V_{DD} | -10 | --- | 10 | uA | |
| Input Leakage Current (MCL) | I_{MLI3} | $V_{MIN} = V_{SS}$ to V_{MIL} (max) | -10 | --- | 10 | uA | |
| Output Leakage Current | I_{LO} | $V_{OUT} = V_{SS}$ to V_{DDQ} | -10 | --- | 10 | uA | |
| Average Power Supply Operating Current (x72) | I_{DD-33} | $I_{OUT} = 0$ mA | --- | --- | 750 | mA | |
| | I_{DD-4} | $V_{IN} = V_{IH}$ or V_{IL} | --- | --- | 650 | | |
| | I_{DD-5} | | --- | --- | 550 | | |
| Average Power Supply Operating Current (x36) | I_{DD-33} | $I_{OUT} = 0$ mA | --- | --- | 580 | mA | |
| | I_{DD-4} | $V_{IN} = V_{IH}$ or V_{IL} | --- | --- | 500 | | |
| | I_{DD-5} | | --- | --- | 420 | | |
| Average Power Supply Operating Current (x18) | I_{DD-33} | $I_{OUT} = 0$ mA | --- | --- | 490 | mA | |
| | I_{DD-4} | $V_{IN} = V_{IH}$ or V_{IL} | --- | --- | 430 | | |
| | I_{DD-5} | | --- | --- | 380 | | |
| Power Supply Deselect Operating Current | I_{DD2} | $I_{OUT} = 0$ mA $V_{IN} = V_{IH}$ or V_{IL} | --- | --- | 250 | mA | |
| Output High Voltage | V_{OH} | $I_{OH} = -6.0$ mA $ZQ = V_{IH}$ | $V_{DDQ} - 0.4$ | --- | --- | V | |
| Output Low Voltage | V_{OL} | $I_{OL} = 6.0$ mA $ZQ = V_{IH}$ | --- | --- | 0.4 | V | |
| Output Driver Impedance | R_{OUT} | $V_{OH}, V_{OL} = V_{DDQ}/2$ $ZQ = V_{IL}$ | 17 | 25 | 33 | Ω | |
| | | $V_{OH}, V_{OL} = V_{DDQ}/2$ $ZQ = V_{IH}$ | 35 | 50 | 65 | Ω | |

•AC Electrical Characteristics
(V_{DD} = 1.8V ± 0.1V, V_{SS} = 0V, T_A = 0 to 85°C)

| Parameter | Symbol | -33 | | -4 | | -5 | | Units | Notes |
|-----------------------------------------|--------------------|-------------------------|-----|-------------------------|-----|-------------------------|-----|-------|-------|
| | | Min | Max | Min | Max | Min | Max | | |
| Input Clock Cycle Time | t _{KHKH} | 3.3 | --- | 4.0 | --- | 5.0 | --- | ns | |
| Input Clock High Pulse Width | t _{KHKL} | 1.3 | --- | 1.5 | --- | 2.0 | --- | ns | |
| Input Clock Low Pulse Width | t _{KLKH} | 1.3 | --- | 1.5 | --- | 2.0 | --- | ns | |
| Address Input Setup Time | t _{AVKH} | 0.7 | --- | 0.8 | --- | 1.0 | --- | ns | |
| Address Input Hold Time | t _{KHAX} | 0.4 | --- | 0.5 | --- | 0.5 | --- | ns | |
| Control Input Setup Time | t _{BVKH} | 0.7 | --- | 0.8 | --- | 1.0 | --- | ns | 1 |
| Control Input Hold Time | t _{KHBX} | 0.4 | --- | 0.5 | --- | 0.5 | --- | ns | 1 |
| Data Input Setup Time | t _{DVKH} | 0.7 | --- | 0.8 | --- | 1.0 | --- | ns | |
| Data Input Hold Time | t _{KHDX} | 0.4 | --- | 0.5 | --- | 0.5 | --- | ns | |
| Input Clock High to Output Data Valid | t _{KHQV} | --- | 1.8 | --- | 2.1 | --- | 2.3 | ns | |
| Input Clock High to Output Data Hold | t _{KHQX} | 0.5 | --- | 0.5 | --- | 0.5 | --- | ns | 2 |
| Input Clock High to Output Data Low-Z | t _{KHQX1} | 0.5 | --- | 0.5 | --- | 0.5 | --- | ns | 2,3 |
| Input Clock High to Output Data High-Z | t _{KHQZ} | --- | 1.8 | --- | 2.1 | --- | 2.3 | ns | 2,3 |
| Input Clock High to Output Clock High | t _{KHCH} | 0.5 | 1.8 | 0.5 | 2.1 | 0.5 | 2.3 | ns | |
| Input Clock High to Output Clock Low-Z | t _{KHCX1} | 0.5 | --- | 0.5 | --- | 0.5 | --- | ns | 2,3 |
| Input Clock High to Output Clock High-Z | t _{KHCZ} | --- | 1.8 | --- | 2.1 | --- | 2.3 | ns | 2,3 |
| Output Clock High to Output Data Valid | t _{CHQV} | --- | 0.4 | --- | 0.5 | --- | 0.6 | ns | 2 |
| Output Clock High to Output Data Hold | t _{CHQX} | -0.4 | --- | -0.5 | --- | -0.6 | --- | ns | 2 |
| Output Clock High Pulse Width | t _{CHCL} | t _{KHKL} ± 0.2 | | t _{KHKL} ± 0.2 | | t _{KHKL} ± 0.2 | | ns | 2 |
| Output Clock Low Pulse Width | t _{CLCH} | t _{KLKH} ± 0.2 | | t _{KLKH} ± 0.2 | | t _{KLKH} ± 0.2 | | ns | 2 |

All parameters are measured from the mid-point of the object signal to the mid-point of the reference signal, unless otherwise noted.

1. These parameters apply to control inputs $\overline{E1}$, E2, E3, ADV, \overline{W} , and \overline{Bx} .
2. These parameters are guaranteed by design through extensive corner lot characterization.
3. These parameters are measured at ± 50mV from steady state voltage.

•AC Electrical Characteristics (Note)

The two AC timing parameters listed below are tested according to specific combinations of Output Clocks (CQs) and Output Data (DQs):

1. t_{CHQV} - Output Clock High to Output Data Valid (max)
2. t_{CHQX} - Output Clock High to Output Data Hold (min)

The specific CQ / DQ combinations are defined as follows:

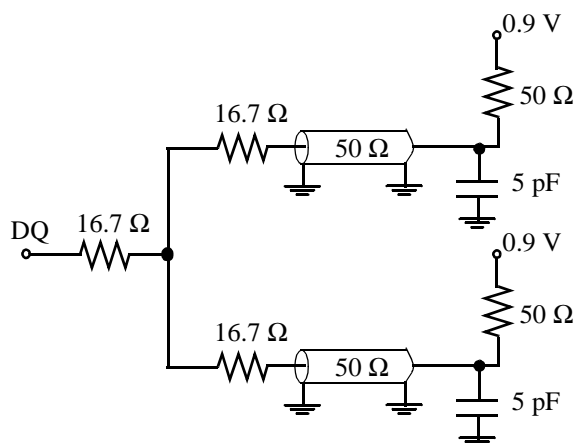
| 256Kb x 72 | | 512Kb x 36 | | 1Mb x 18 | |
|------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------------|---------------------------------------------------------------------------------------------------|----------|------------------------------------------------|
| CQs | DQs | CQs | DQs | CQs | DQs |
| 1K, 2K | 1A, 2A, 1B, 2B, 1C, 2C, 1D, 2D, 1E, 2E, 1F, 2F, 1G, 2G, 1H, 2H, 1J, 2J, 1L, 2L, 1M, 2M, 1N, 2N, 1P, 2P, 2R, 1R, 1T, 2T, 1U, 2U, 1V, 2V, 1W, 2W | 1K, 2K | 2E, 1F, 2F, 1G, 2G, 1H, 2H, 1J, 2J, 1R, 1T, 2T, 1U, 2U, 1V, 2V, 1W, 2W | 1K, 2K | 2E, 1F, 2F, 1G, 2G, 1H, 2H, 1J, 2J |
| 10K, 11K | 10A, 11A, 10B, 11B, 10C, 11C, 10D, 11D, 11E, 10E, 10F, 11F, 10G, 11G, 10H, 11H, 10J, 11J, 10L, 11L, 10M, 11M, 10N, 11N, 10P, 11P, 10R, 11R, 10T, 11T, 10U, 11U, 10V, 11V, 10W, 11W | 10K, 11K | 10A, 11A, 10B, 11B, 10C, 11C, 10D, 11D, 11E, 10L, 11L, 10M, 11M, 10N, 11N, 10P, 11P, 10R | 10K, 11K | 10L, 11L, 10M, 11M, 10N, 11N, 10P, 11P, 10R |

•AC Test Conditions ($V_{DDQ} = 1.8V$)

($V_{DD} = 1.8V \pm 0.1V$, $V_{DDQ} = 1.8V \pm 0.1V$, $T_A = 0$ to $85^\circ C$)

| Parameter | Symbol | Conditions | Units | Notes |
|------------------------------|-----------|---------------|-------|--------------------|
| Input High Level | V_{IH} | 1.4 | V | |
| Input Low Level | V_{IL} | 0.4 | V | |
| Input Rise & Fall Time | | 2.0 | V/ns | |
| Input Reference Level | | 0.9 | V | |
| Clock Input High Voltage | V_{KIH} | 1.4 | V | |
| Clock Input Low Voltage | V_{KIL} | 0.4 | V | |
| Clock Input Rise & Fall Time | | 2.0 | V/ns | |
| Clock Input Reference Level | | 0.9 | V | |
| Output Reference Level | | 0.9 | V | |
| Output Load Conditions | | $ZQ = V_{IH}$ | | See Figure 1 below |

Figure 1: AC Test Output Load ($V_{DDQ} = 1.8V$)

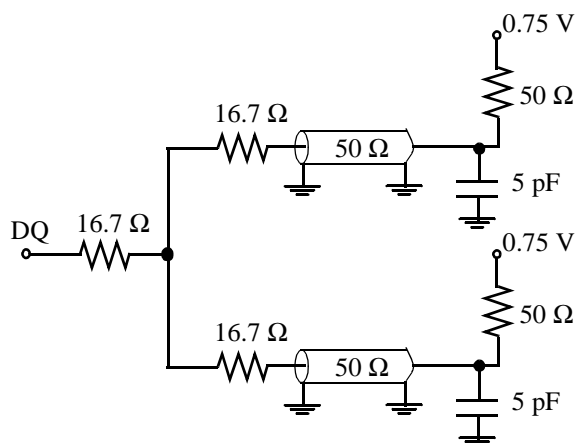


•AC Test Conditions ($V_{DDQ} = 1.5V$)

($V_{DD} = 1.8V \pm 0.1V$, $V_{DDQ} = 1.5V \pm 0.1V$, $T_A = 0$ to $85^\circ C$)

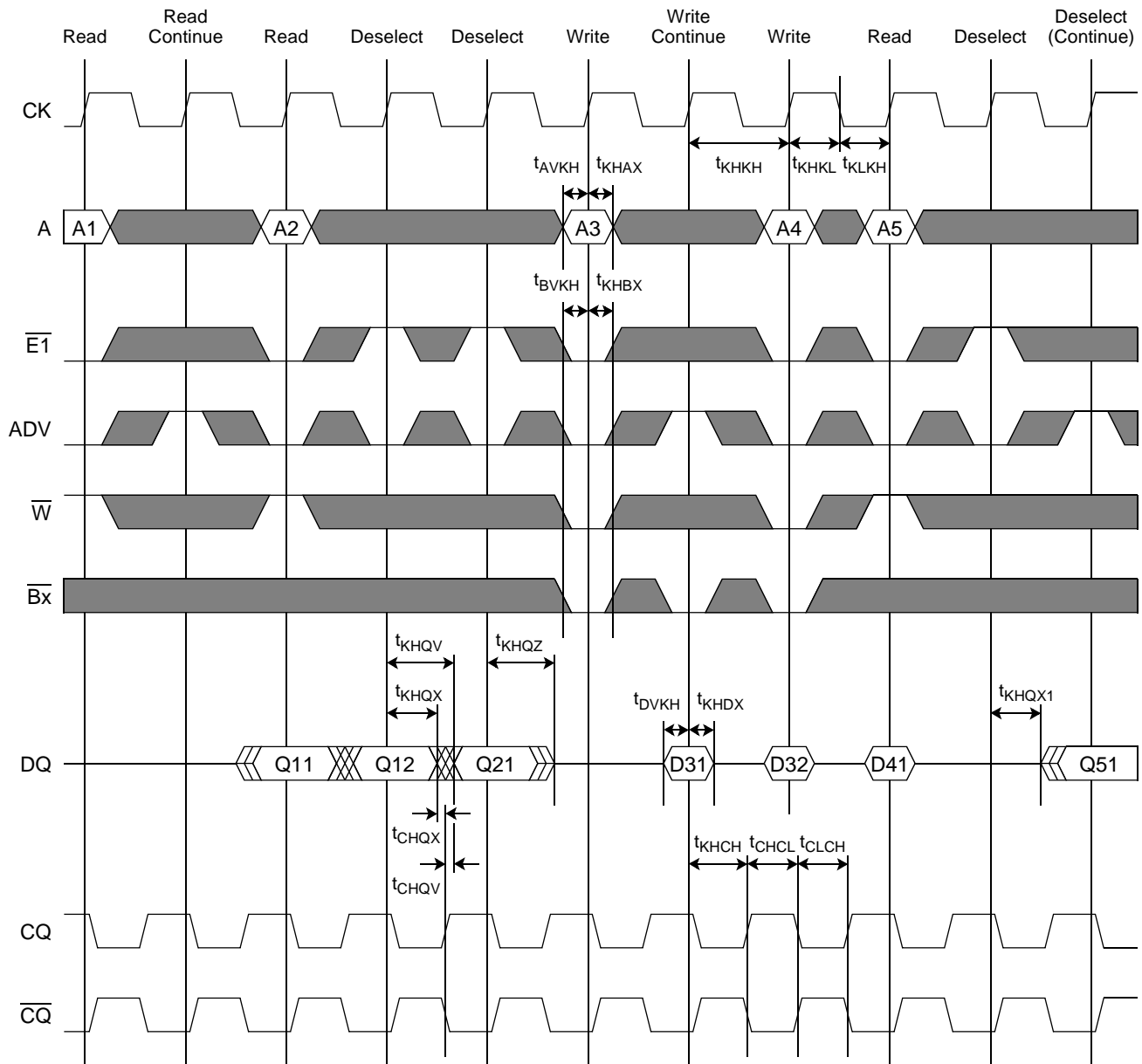
| Parameter | Symbol | Conditions | Units | Notes |
|------------------------------|-----------|---------------|-------|--------------------|
| Input High Level | V_{IH} | 1.25 | V | |
| Input Low Level | V_{IL} | 0.25 | V | |
| Input Rise & Fall Time | | 2.0 | V/ns | |
| Input Reference Level | | 0.75 | V | |
| Clock Input High Voltage | V_{KIH} | 1.25 | V | |
| Clock Input Low Voltage | V_{KIL} | 0.25 | V | |
| Clock Input Rise & Fall Time | | 2.0 | V/ns | |
| Clock Input Reference Level | | 0.75 | V | |
| Output Reference Level | | 0.75 | V | |
| Output Load Conditions | | $ZQ = V_{IH}$ | | See Figure 2 below |

Figure 2: AC Test Output Load ($V_{DDQ} = 1.5V$)



One Bank Read-Write-Read Timing Diagram

Figure 3

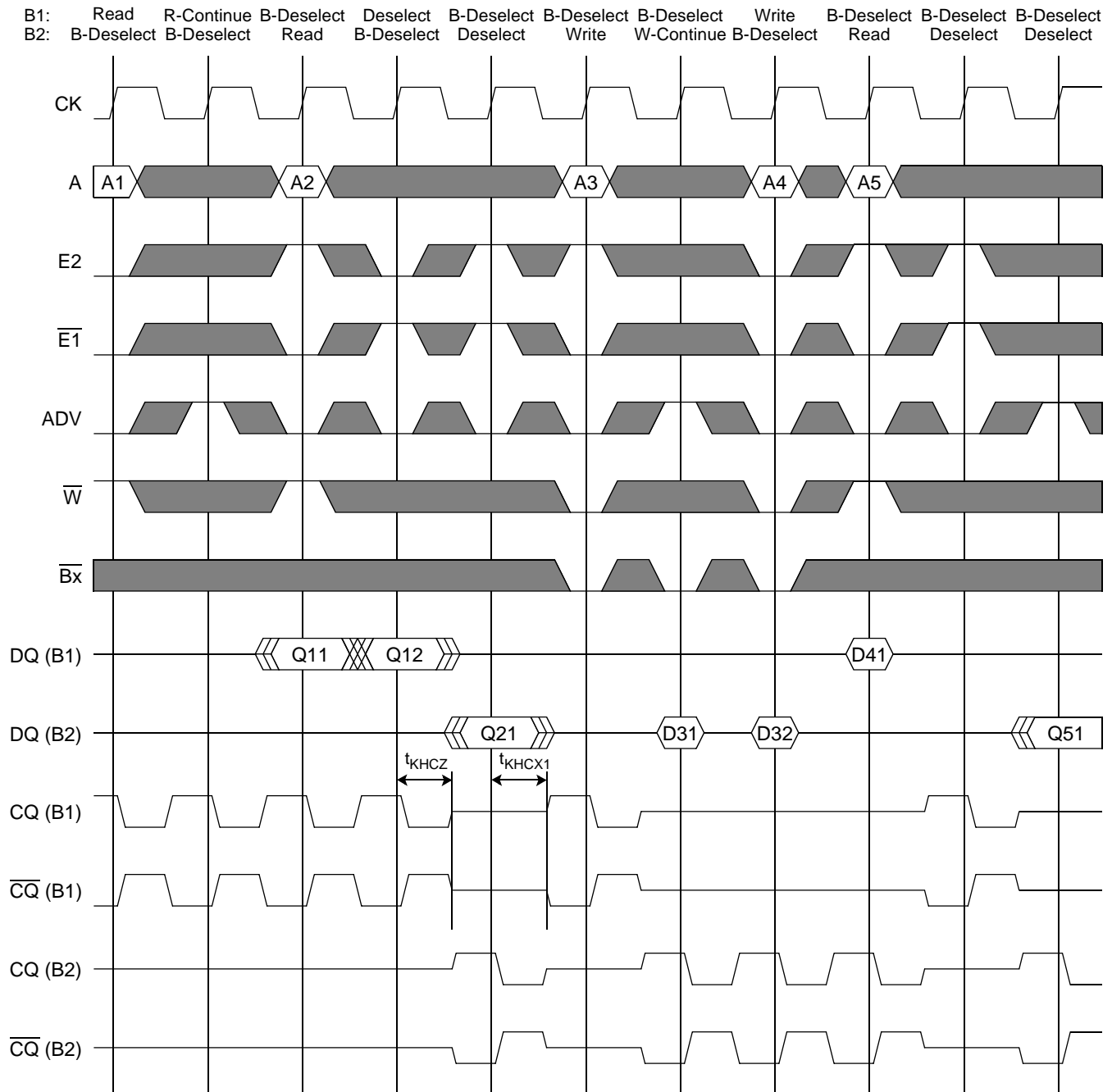


Note: In the diagram above, two Deselect operations are inserted between Read and Write operations to control the data bus transition from output to input. This depiction is for clarity purposes only. It is NOT a requirement. Depending on the application, one Deselect operation may be sufficient.

Note: E1 = EP1 and E2 = EP2 in this example (not shown).

Two Bank Read-Write-Read Timing Diagram

Figure 4



Note: In the diagram above, two Deselect operations are inserted between Read and Write operations to control the data bus transition from output to input. This depiction is for clarity purposes only. It is NOT a requirement. Depending on the application, one Deselect operation may be sufficient.

Note: Bank 1 EP1 = "low", Bank 2 EP1 = "high", and Bank 1 and Bank 2 E2 = EP2 in this example (not shown).

•Test Mode Description

These devices provide a JTAG Test Access Port (TAP) and Boundary Scan interface using a limited set of IEEE std. 1149.1 functions. This test mode is intended to provide a mechanism for testing the interconnect between master (processor, controller, etc.), SRAMs, other components, and the printed circuit board.

In conformance with a subset of IEEE std. 1149.1, these devices contain a TAP Controller and four TAP Registers. The TAP Registers consist of one Instruction Register and three Data Registers (ID, Bypass, and Boundary Scan Registers).

The TAP consists of the following four signals:

| | | |
|------|------------------|------------------------------------------------------------------------------------|
| TCK: | Test Clock | Induces (clocks) TAP Controller state transitions. |
| TMS: | Test Mode Select | Inputs commands to the TAP Controller. Sampled on the rising edge of TCK. |
| TDI: | Test Data In | Inputs data serially to the TAP Registers. Sampled on the rising edge of TCK. |
| TDO: | Test Data Out | Outputs data serially from the TAP Registers. Driven from the falling edge of TCK. |

Disabling the TAP

When JTAG is not used, TCK should be tied “low” to prevent clocking the SRAM. TMS and TDI should either be tied “high” through a pull-up resistor or left unconnected. TDO should be left unconnected.

Note: Operation of the TAP does not disrupt normal SRAM operation except when the EXTEST-A or SAMPLE-Z instruction is selected. Consequently, TCK, TMS, and TDI can be controlled any number of ways without adversely affecting the functionality of the device.

JTAG DC Recommended Operating Conditions

($V_{DD} = 1.8V \pm 0.1V$, $T_A = 0$ to $85^\circ C$)

| Parameter | Symbol | Test Conditions | Min | Max | Units |
|-----------------------------------------|-----------|---------------------------------|------------------|------------------|---------|
| JTAG Input High Voltage (TCK, TMS, TDI) | V_{TIH} | --- | $V_{DD}/2 + 0.3$ | $V_{DD} + 0.3$ | V |
| JTAG Input Low Voltage (TCK, TMS, TDI) | V_{TIL} | --- | -0.3 | $V_{DD}/2 - 0.3$ | V |
| JTAG Output High Voltage (TDO) | V_{TOH} | $I_{TOH} = -100\mu A$ | $V_{DD} - 0.1$ | --- | V |
| JTAG Output Low Voltage (TDO) | V_{TOL} | $I_{TOL} = 100\mu A$ | --- | 0.1 | V |
| JTAG Output High Voltage (TDO) | V_{TOH} | $I_{TOH} = -8mA$ | $V_{DD} - 0.4$ | --- | V |
| JTAG Output Low Voltage (TDO) | V_{TOL} | $I_{TOL} = 8mA$ | --- | 0.4 | V |
| JTAG Input Leakage Current | I_{TLI} | $V_{TIN} = V_{SS}$ to V_{DD} | -20 | 10 | μA |
| JTAG Output Leakage Current | I_{TLO} | $V_{TOUT} = V_{SS}$ to V_{DD} | -10 | 10 | μA |

JTAG AC Test Conditions

($V_{DD} = 1.8V \pm 0.1V$, $T_A = 0$ to $85^\circ C$)

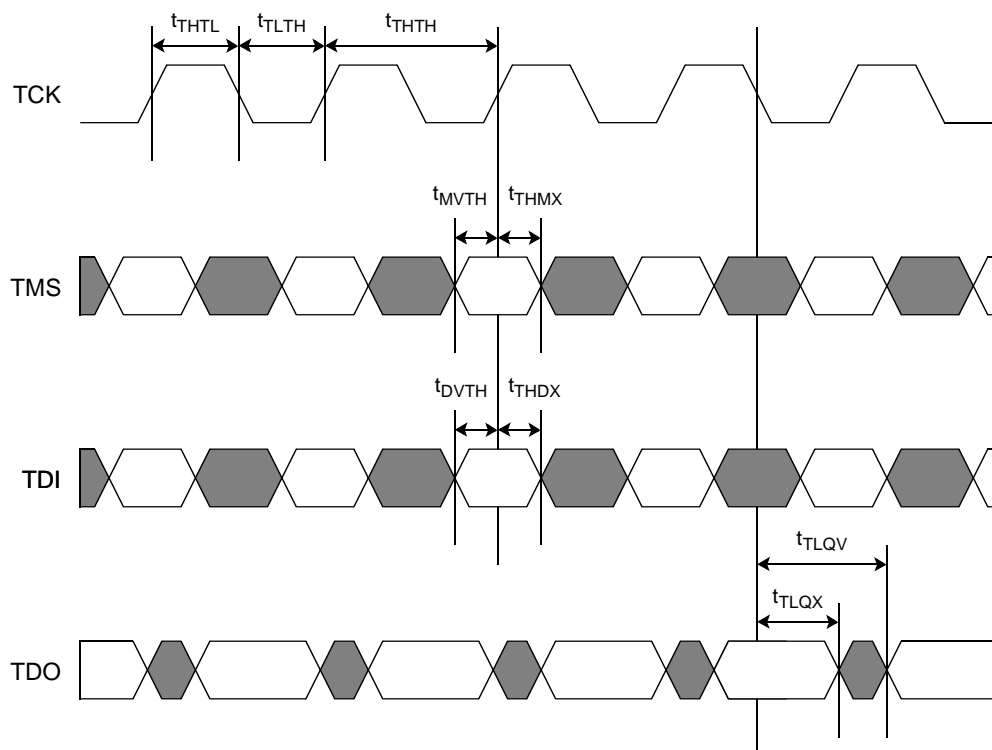
| Parameter | Symbol | Conditions | Units | Notes |
|-----------------------------|-----------|------------|-------|----------------------|
| JTAG Input High Level | V_{TIH} | 1.8 | V | |
| JTAG Input Low Level | V_{TIL} | 0.0 | V | |
| JTAG Input Rise & Fall Time | | 1.0 | V/ns | |
| JTAG Input Reference Level | | 0.9 | V | |
| JTAG Output Reference Level | | 0.9 | V | |
| JTAG Output Load Condition | | | | See Fig. 1 (page 15) |

JTAG AC Electrical Characteristics

| Parameter | Symbol | Min | Max | Units |
|----------------------------------------------------|-------------------|-----|-----|-------|
| TCK Cycle Time | t_{THTH} | 50 | | ns |
| TCK High Pulse Width | t_{HTL} | 20 | | ns |
| TCK Low Pulse Width | t_{LTH} | 20 | | ns |
| TMS Setup Time | t_{MVTH} | 5 | | ns |
| TMS Hold Time | t_{THMX} | 5 | | ns |
| TDI Setup Time | t_{DVTH} | 5 | | ns |
| TDI Hold Time | t_{THDX} | 5 | | ns |
| Capture Setup Time (Address, Control, Data, Clock) | t_{CS} | 5 | | ns |
| Capture Hold Time (Address, Control, Data, Clock) | t_{CH} | 5 | | ns |
| TCK Low to TDO Valid | t_{TLQV} | | 10 | ns |
| TCK Low to TDO Hold | t_{TLQX} | 0 | | ns |

JTAG Timing Diagram

Figure 5



TAP Controller

The TAP Controller is a 16-state state machine that controls access to the various TAP Registers and executes the operations associated with each TAP Instruction (see Figure 7 below). State transitions are controlled by TMS and occur on the rising edge of TCK.

The TAP Controller enters the “Test-Logic Reset” state in one of two ways:

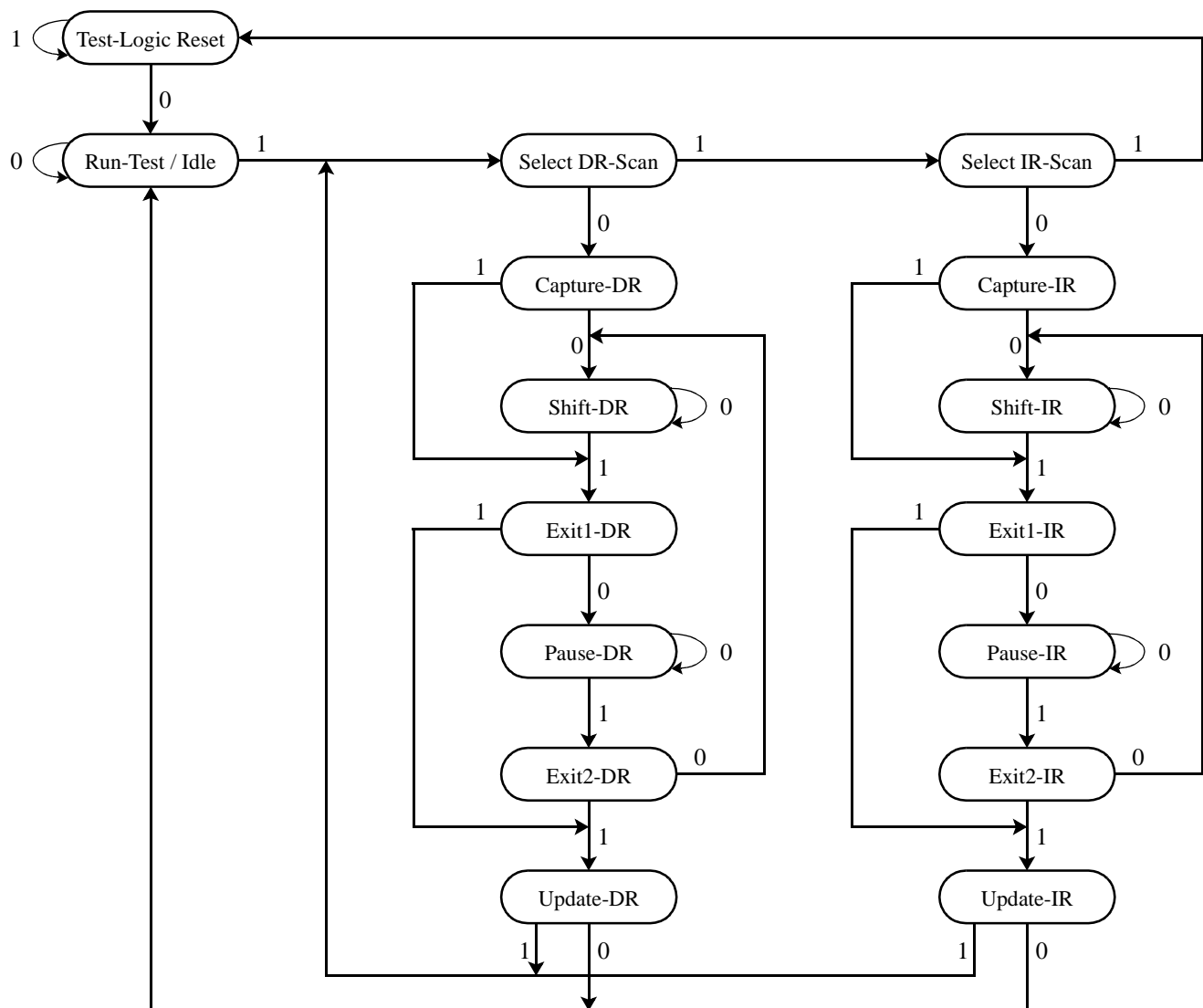
1. At power up.
2. When a logic “1” is applied to TMS for at least 5 consecutive rising edges of TCK.

The TDI input receiver is sampled only when the TAP Controller is in either the “Shift-IR” state or the “Shift-DR” state.

The TDO output driver is active only when the TAP Controller is in either the “Shift-IR” state or the “Shift-DR” state.

TAP Controller State Diagram

Figure 6



TAP Registers

TAP Registers are serial shift registers that capture serial input data (from TDI) on the rising edge of TCK, and drive serial output data (to TDO) on the subsequent falling edge of TCK. They are divided into two groups: “Instruction Registers” (IR), which are manipulated via the “IR” states in the TAP Controller, and “Data Registers” (DR), which are manipulated via the “DR” states in the TAP Controller.

Instruction Register (IR - 3 bits)

The Instruction Register stores the various TAP Instructions supported by these devices. It is loaded with the IDCODE instruction at power-up, and when the TAP Controller is in the “Test-Logic Reset” and “Capture-IR” states. It is inserted between TDI and TDO when the TAP Controller is in the “Shift-IR” state, at which time it can be loaded with a new instruction. However, newly loaded instructions are not executed until the TAP Controller has reached the “Update-IR” state.

The Instruction Register is 3 bits wide, and is encoded as follows:

| Code (2:0) | Instruction | Description |
|---------------|-------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 000 | EXTEST-A | Loads the individual logic states of all signals composing the SRAM’s I/O ring into the Boundary Scan Register when the TAP Controller is in the “Capture-DR” state, and inserts the B-Scan Register between TDI and TDO when the TAP Controller is in the “Shift-DR” state. Also enables the SRAM’s data and clock output drivers, and moves the contents of the B-Scan Register associated with the data and clock output signals to the input side of the SRAM’s output register. The SRAM’s input clock can then be used to transfer the B-Scan Register contents directly to the data and clock output pins (the input clock controls the SRAM’s output register). Note that newly captured and/or shifted B-Scan Register contents do not appear at the input side of the SRAM’s output register until the TAP Controller has reached the “Update-DR” state. See the Boundary Scan Register description for more information. |
| 001 | IDCODE | Loads a predefined device- and manufacturer-specific identification code into the ID Register when the TAP Controller is in the “Capture-DR” state, and inserts the ID Register between TDI and TDO when the TAP Controller is in the “Shift-DR” state. See the ID Register description for more information. |
| 010 | SAMPLE-Z | Loads the individual logic states of all signals composing the SRAM’s I/O ring into the Boundary Scan Register when the TAP Controller is in the “Capture-DR” state, and inserts the B-Scan Register between TDI and TDO when the TAP Controller is in the “Shift-DR” state. Also disables the SRAM’s data and clock output drivers. See the Boundary Scan Register description for more information. |
| 011 | PRIVATE | Do not use. Reserved for manufacturer use only. |
| 100 | SAMPLE | Loads the individual logic states of all signals composing the SRAM’s I/O ring into the Boundary Scan Register when the TAP Controller is in the “Capture-DR” state, and inserts the Boundary Scan Register between TDI and TDO when the TAP Controller is in the “Shift-DR” state. See the Boundary Scan Register description for more information. |
| 101 | PRIVATE | Do not use. Reserved for manufacturer use only. |
| 110 | PRIVATE | Do not use. Reserved for manufacturer use only. |
| 111 | BYPASS | Loads a logic “0” into the Bypass Register when the TAP Controller is in the “Capture-DR” state, and inserts the Bypass Register between TDI and TDO when the TAP Controller is in the “Shift-DR” state. See the Bypass Register description for more information. |

Bit 0 is the LSB of the Instruction Register, and Bit 2 is the MSB. When the Instruction Register is selected, TDI serially shifts data into the MSB, and the LSB serially shifts data out through TDO.

Bypass Register (DR - 1 bit)

The Bypass Register is one bit wide, and provides the minimum length serial path between TDI and TDO. It is loaded with a logic “0” when the BYPASS instruction has been loaded in the Instruction Register and the TAP Controller is in the “Capture-DR” state. It is inserted between TDI and TDO when the BYPASS instruction has been loaded into the Instruction Register and the TAP Controller is in the “Shift-DR” state.

ID Register (DR - 32 bits)

The ID Register is loaded with a predetermined device- and manufacturer-specific identification code when the IDCODE instruction has been loaded into the Instruction Register and the TAP Controller is in the “Capture-DR” state. It is inserted between TDI and TDO when the IDCODE instruction has been loaded into the Instruction Register and the TAP Controller is in the “Shift-DR” state.

The ID Register is 32 bits wide, and is encoded as follows:

| Device | Revision Number (31:28) | Part Number (27:12) | Sony ID (11:1) | Start Bit (0) |
|------------|----------------------------|------------------------|-------------------|------------------|
| 256Kb x 72 | xxxx | 0000 0000 0101 0110 | 0000 1110 001 | 1 |
| 512Kb x 36 | xxxx | 0000 0000 0101 1010 | 0000 1110 001 | 1 |
| 1Mb x 18 | xxxx | 0000 0000 0110 0000 | 0000 1110 001 | 1 |

Bit 0 is the LSB of the ID Register, and Bit 31 is the MSB. When the ID Register is selected, TDI serially shifts data into the MSB, and the LSB serially shifts data out through TDO.

Boundary Scan Register (DR - 123 bits for x72, 84 bits for x36, 65 bits for x18)

The Boundary Scan Register is equal in length to the number of active signal connections to the SRAM (excluding the TAP pins) plus a number of place holder locations reserved for functional and/or density upgrades. It is loaded with the individual logic states of all signals composing the SRAM’s I/O ring when the EXTEST-A, SAMPLE, or SAMPLE-Z instruction has been loaded into the Instruction Register and the TAP Controller is in the “Capture-DR” state. It is inserted between TDI and TDO when the EXTEST-A, SAMPLE, or SAMPLE-Z instruction has been loaded into the Instruction Register and the TAP Controller is in the “Shift-DR” state.

The Boundary Scan Register contains the following bits:

| 256Kb x 72 | | 512Kb x 36 | | 1Mb x 18 | |
|------------------------------------------------------------------------------|----|------------------------------------------------------------------------------|----|------------------------------------------------------------------------------|----|
| DQx | 72 | DQx | 36 | DQx | 18 |
| A, A1, A0 | 18 | A, A1, A0 | 19 | A, A1, A0 | 20 |
| CK | 1 | CK | 1 | CK | 1 |
| CQ1, CQ2, $\overline{\text{CQ1}}$, $\overline{\text{CQ2}}$ | 4 | CQ1, CQ2, $\overline{\text{CQ1}}$, $\overline{\text{CQ2}}$ | 4 | CQ1, CQ2, $\overline{\text{CQ1}}$, $\overline{\text{CQ2}}$ | 4 |
| $\overline{\text{E1}}$, ADV, $\overline{\text{W}}$, $\overline{\text{Bx}}$ | 11 | $\overline{\text{E1}}$, ADV, $\overline{\text{W}}$, $\overline{\text{Bx}}$ | 7 | $\overline{\text{E1}}$, ADV, $\overline{\text{W}}$, $\overline{\text{Bx}}$ | 5 |
| E2, E3, EP2, EP3 | 4 | E2, E3, EP2, EP3 | 4 | E2, E3, EP2, EP3 | 4 |
| ZQ | 1 | ZQ | 1 | ZQ | 1 |
| Place Holder | 12 | Place Holder | 12 | Place Holder | 12 |

Boundary Scan Register Bit Order Assignments

The tables below depict the order in which the bits are arranged in the Boundary Scan Register. Bit 1 is the LSB and bit 123 (for x72) or bit 84 (for x36) or bit 65 (for x18) is the MSB. When the Boundary Scan Register is selected, TDI serially shifts data into the MSB, and the LSB serially shifts data out through TDO.

| 256Kb x 72 | | | | | | | | | | | |
|------------|-------------------------|-----|--|-----|------------------------|-----|--|-----|-------------------------|-----|--|
| Bit | Signal | Pad | | Bit | Signal | Pad | | Bit | Signal | Pad | |
| 1 | NC ⁽¹⁾ | 5C | | 36 | DQf | 11G | | 71 | DQg | 1A | |
| 2 | NC ⁽¹⁾ | 5U | | 37 | DQf | 10F | | 72 | DQg | 1B | |
| 3 | NC ⁽¹⁾ | 7U | | 38 | DQf | 11F | | 73 | DQg | 2B | |
| 4 | MCL ⁽¹⁾ | 6D | | 39 | DQf | 10E | | 74 | DQg | 1C | |
| 5 | MCL ⁽¹⁾ | 6K | | 40 | DQb | 11E | | 75 | DQg | 2C | |
| 6 | MCL ⁽¹⁾ | 6P | | 41 | DQb | 10D | | 76 | DQg | 1D | |
| 7 | MCL ⁽¹⁾ | 6T | | 42 | DQb | 11D | | 77 | DQg | 2D | |
| 8 | MCH ⁽²⁾ | 6N | | 43 | DQb | 10C | | 78 | DQg | 1E | |
| 9 | MCH | 6M | | 44 | DQb | 11C | | 79 | DQc | 2E | |
| 10 | MCH | 6L | | 45 | DQb | 10B | | 80 | DQc | 1F | |
| 11 | DQe | 10W | | 46 | DQb | 11B | | 81 | DQc | 2F | |
| 12 | DQe | 11W | | 47 | DQb | 11A | | 82 | DQc | 1G | |
| 13 | DQe | 11V | | 48 | DQb | 10A | | 83 | DQc | 2G | |
| 14 | DQe | 10V | | 49 | $\overline{\text{Bf}}$ | 9B | | 84 | DQc | 1H | |
| 15 | DQe | 11U | | 50 | $\overline{\text{Ba}}$ | 9C | | 85 | DQc | 2H | |
| 16 | DQe | 10U | | 51 | $\overline{\text{Bb}}$ | 8B | | 86 | DQc | 1J | |
| 17 | DQe | 11T | | 52 | $\overline{\text{Be}}$ | 8C | | 87 | DQc | 2J | |
| 18 | DQe | 10T | | 53 | EP3 | 6H | | 88 | CQ2 | 1K | |
| 19 | DQe | 11R | | 54 | EP2 | 6G | | 89 | CK | 3K | |
| 20 | DQa | 10R | | 55 | A | 9A | | 90 | NC ⁽¹⁾ | 4K | |
| 21 | DQa | 11P | | 56 | E3 | 8A | | 91 | $\overline{\text{CQ2}}$ | 2K | |
| 22 | DQa | 10P | | 57 | A | 7B | | 92 | DQh | 2L | |
| 22 | DQa | 11N | | 58 | A | 7A | | 93 | DQh | 1L | |
| 24 | DQa | 10N | | 59 | $\overline{\text{W}}$ | 6B | | 94 | DQh | 2M | |
| 25 | DQa | 11M | | 60 | ADV | 6A | | 95 | DQh | 1M | |
| 26 | DQa | 10M | | 61 | $\overline{\text{E1}}$ | 6C | | 96 | DQh | 2N | |
| 27 | DQa | 11L | | 62 | A | 5A | | 97 | DQh | 1N | |
| 28 | DQa | 10L | | 63 | E2 | 4A | | 98 | DQh | 2P | |
| 29 | CQ1 | 11K | | 64 | A | 3A | | 99 | DQh | 1P | |
| 30 | $\overline{\text{CQ1}}$ | 10K | | 65 | ZQ | 6F | | 100 | DQh | 2R | |
| 31 | DQf | 10J | | 66 | $\overline{\text{Bd}}$ | 4C | | 101 | DQd | 1R | |
| 32 | DQf | 11J | | 67 | $\overline{\text{Bg}}$ | 4B | | 102 | DQd | 2T | |
| 33 | DQf | 10H | | 68 | $\overline{\text{Bh}}$ | 3C | | 103 | DQd | 1T | |
| 34 | DQf | 11H | | 69 | $\overline{\text{Bc}}$ | 3B | | 104 | DQd | 2U | |
| 35 | DQf | 10G | | 70 | DQg | 2A | | 105 | DQd | 1U | |

Note 1: NC and MCL pins at pad locations 5C, 5U, 7U, 6D, 6K, 6P, 6T, and 4K are connected to V_{SS} internally, regardless of pin connection externally.

Note 2: MCH pin at pad location 6N is connected to V_{DD} internally, regardless of pin connection externally.

| 512Kb x 36 | | | | | | | | |
|------------|--------------------|-----|-----|-------------------|-----|-----|--------|-----|
| Bit | Signal | Pad | Bit | Signal | Pad | Bit | Signal | Pad |
| 1 | NC ⁽¹⁾ | 5C | 36 | E3 | 8A | 71 | MCL | 6J |
| 2 | NC ⁽¹⁾ | 5U | 37 | A | 7B | 72 | A | 3V |
| 3 | NC ⁽¹⁾ | 7U | 38 | A | 7A | 73 | A | 4V |
| 4 | MCL ⁽¹⁾ | 6D | 39 | \overline{W} | 6B | 74 | A | 4U |
| 5 | MCL ⁽¹⁾ | 6K | 40 | ADV | 6A | 75 | A | 5V |
| 6 | MCL ⁽¹⁾ | 6P | 41 | \overline{EI} | 6C | 76 | A | 6U |
| 7 | MCL ⁽¹⁾ | 6T | 42 | A | 5A | 77 | A | 5W |
| 8 | MCH ⁽²⁾ | 6N | 43 | A | 5B | 78 | A0 | 6W |
| 9 | MCH | 6M | 44 | E2 | 4A | 79 | A1 | 6V |
| 10 | MCH | 6L | 45 | A | 3A | 80 | A | 7V |
| 11 | DQa | 10R | 46 | ZQ | 6F | 81 | A | 8V |
| 12 | DQa | 11P | 47 | \overline{Bd} | 4C | 82 | A | 7W |
| 13 | DQa | 10P | 48 | \overline{Bc} | 3B | 83 | A | 8U |
| 14 | DQa | 11N | 49 | DQc | 2E | 84 | A | 9V |
| 15 | DQa | 10N | 50 | DQc | 1F | | | |
| 16 | DQa | 11M | 51 | DQc | 2F | | | |
| 17 | DQa | 10M | 52 | DQc | 1G | | | |
| 18 | DQa | 11L | 53 | DQc | 2G | | | |
| 19 | DQa | 10L | 54 | DQc | 1H | | | |
| 20 | CQ1 | 11K | 55 | DQc | 2H | | | |
| 21 | $\overline{CQ1}$ | 10K | 56 | DQc | 1J | | | |
| 22 | DQb | 11E | 57 | DQc | 2J | | | |
| 22 | DQb | 10D | 58 | CQ2 | 1K | | | |
| 24 | DQb | 11D | 59 | CK | 3K | | | |
| 25 | DQb | 10C | 60 | NC ⁽¹⁾ | 4K | | | |
| 26 | DQb | 11C | 61 | $\overline{CQ2}$ | 2K | | | |
| 27 | DQb | 10B | 62 | DQd | 1R | | | |
| 28 | DQb | 11B | 63 | DQd | 2T | | | |
| 29 | DQb | 11A | 64 | DQd | 1T | | | |
| 30 | DQb | 10A | 65 | DQd | 2U | | | |
| 31 | \overline{Ba} | 9C | 66 | DQd | 1U | | | |
| 32 | \overline{Bb} | 8B | 67 | DQd | 2V | | | |
| 33 | EP3 | 6H | 68 | DQd | 1V | | | |
| 34 | EP2 | 6G | 69 | DQd | 1W | | | |
| 35 | A | 9A | 70 | DQd | 2W | | | |

Note 1: NC and MCL pins at pad locations 5C, 5U, 7U, 6D, 6K, 6P, 6T, and 4K are connected to V_{SS} internally, regardless of pin connection externally.

Note 2: MCH pin at pad location 6N is connected to V_{DD} internally, regardless of pin connection externally.

| 1Mb x 18 | | | | | |
|----------|-------------------------|-----|-----|-------------------------|-----|
| Bit | Signal | Pad | Bit | Signal | Pad |
| 1 | NC ⁽¹⁾ | 5C | 36 | A | 3A |
| 2 | NC ⁽¹⁾ | 5U | 37 | ZQ | 6F |
| 3 | NC ⁽¹⁾ | 7U | 38 | $\overline{\text{Bb}}$ | 3B |
| 4 | MCL ⁽¹⁾ | 6D | 39 | DQb | 2E |
| 5 | MCL ⁽¹⁾ | 6K | 40 | DQb | 1F |
| 6 | MCL ⁽¹⁾ | 6P | 41 | DQb | 2F |
| 7 | MCL ⁽¹⁾ | 6T | 42 | DQb | 1G |
| 8 | MCH ⁽²⁾ | 6N | 43 | DQb | 2G |
| 9 | MCH | 6M | 44 | DQb | 1H |
| 10 | MCH | 6L | 45 | DQb | 2H |
| 11 | DQa | 10R | 46 | DQb | 1J |
| 12 | DQa | 11P | 47 | DQb | 2J |
| 13 | DQa | 10P | 48 | CQ2 | 1K |
| 14 | DQa | 11N | 49 | CK | 3K |
| 15 | DQa | 10N | 50 | NC ⁽¹⁾ | 4K |
| 16 | DQa | 11M | 51 | $\overline{\text{CQ2}}$ | 2K |
| 17 | DQa | 10M | 52 | MCL | 6J |
| 18 | DQa | 11L | 53 | A | 3V |
| 19 | DQa | 10L | 54 | A | 4V |
| 20 | CQ1 | 11K | 55 | A | 4U |
| 21 | $\overline{\text{CQ1}}$ | 10K | 56 | A | 5V |
| 22 | $\overline{\text{Ba}}$ | 9C | 57 | A | 6U |
| 22 | EP3 | 6H | 58 | A | 5W |
| 24 | EP2 | 6G | 59 | A0 | 6W |
| 25 | A | 9A | 60 | A1 | 6V |
| 26 | E3 | 8a | 61 | A | 7V |
| 27 | A | 7C | 62 | A | 8V |
| 28 | A | 7B | 63 | A | 7W |
| 29 | A | 7A | 64 | A | 8U |
| 30 | $\overline{\text{W}}$ | 6B | 65 | A | 9V |
| 31 | ADV | 6A | | | |
| 32 | $\overline{\text{E1}}$ | 6C | | | |
| 33 | A | 5A | | | |
| 34 | A | 5B | | | |
| 35 | E2 | 4A | | | |

Note 1: NC and MCL pins at pad locations 5C, 5U, 7U, 6D, 6K, 6P, 6T, and 4K are connected to V_{SS} internally, regardless of pin connection externally.

Note 2: MCH pin at pad location 6N is connected to V_{DD} internally, regardless of pin connection externally.

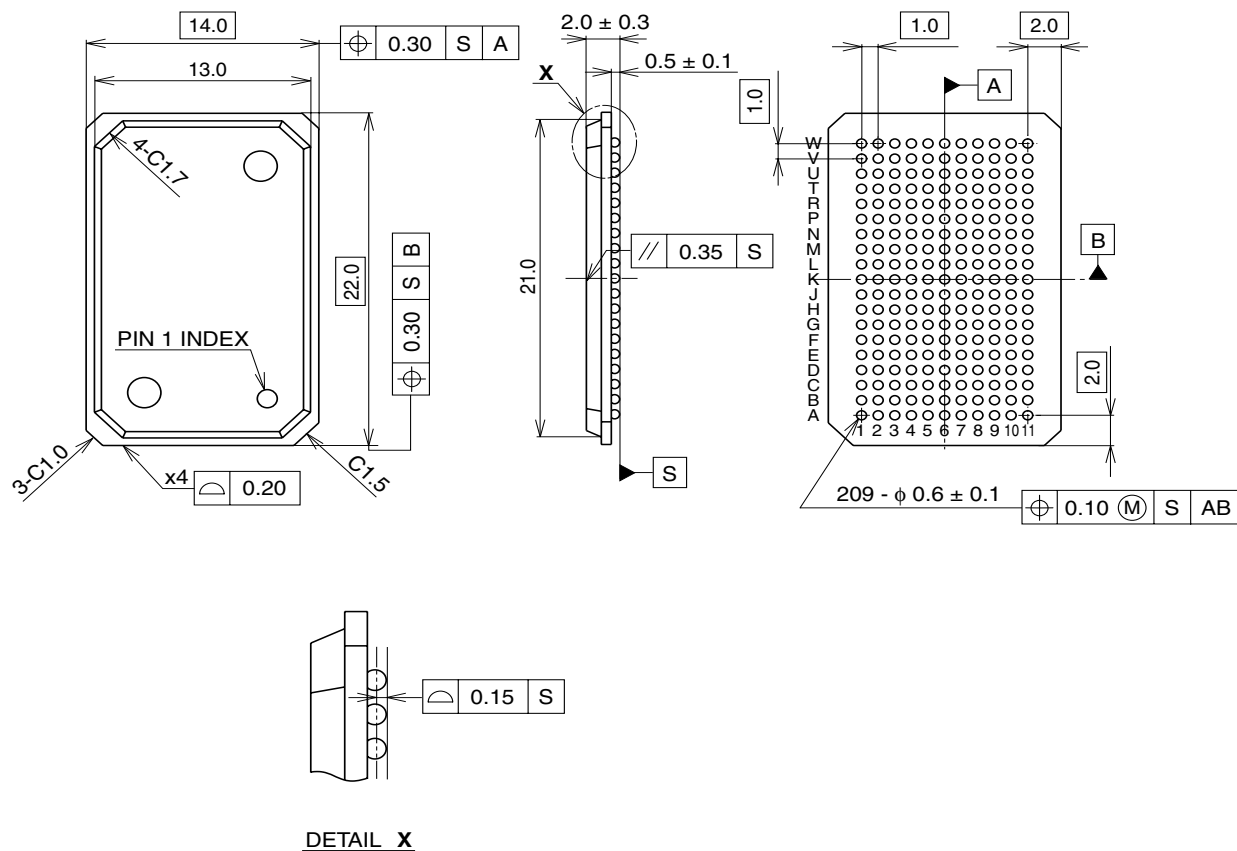
•Ordering Information

| Part Number | V _{DD} | I/O Type | Configuration | Speed (Cycle Time / Data Access Time) |
|-------------------|-----------------|----------|---------------|------------------------------------------|
| CXK79M72C161GB-33 | 1.8V | LVC MOS | 256Kb x 72 | 3.3ns / 1.8ns |
| CXK79M72C161GB-4 | 1.8V | LVC MOS | 256Kb x 72 | 4.0ns / 2.1ns |
| CXK79M72C161GB-5 | 1.8V | LVC MOS | 256Kb x 72 | 5.0ns / 2.3ns |
| CXK79M36C161GB-33 | 1.8V | LVC MOS | 512Kb x 36 | 3.3ns / 1.8ns |
| CXK79M36C161GB-4 | 1.8V | LVC MOS | 512Kb x 36 | 4.0ns / 2.1ns |
| CXK79M36C161GB-5 | 1.8V | LVC MOS | 512Kb x 36 | 5.0ns / 2.3ns |
| CXK79M18C161GB-33 | 1.8V | LVC MOS | 1Mb x 18 | 3.3ns / 1.8ns |
| CXK79M18C161GB-4 | 1.8V | LVC MOS | 1Mb x 18 | 4.0ns / 2.1ns |
| CXK79M18C161GB-5 | 1.8V | LVC MOS | 1Mb x 18 | 5.0ns / 2.3ns |

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•(11x19) 209 Pin BGA Package Dimensions

209PIN BGA (PLASTIC)



PRELIMINARY

| | |
|------------|--------------------|
| SONY CODE | BGA-209P-01 |
| JEITA CODE | P-BGA209-14X22-1.0 |
| JEDEC CODE | _____ |

PACKAGE STRUCTURE

| | |
|--------------------|----------------------|
| PACKAGE MATERIAL | EPOXY RESIN |
| TERMINAL TREATMENT | COPPER-CLAD LAMINATE |
| TERMINAL MATERIAL | SOLDER |
| PACKAGE MASS | 1.1g |

•Revision History

| Rev. # | Rev. Date | Description of Modifications | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
|----------------------------------|--------------------------------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|----------------------------------|-------------------------------------|-------------------------------------------|-------------------------------------|---------------------|-------------------------------------------|---------------------|-------------------------------------|----------|-------------------------------------|--------|-------------------------------------|--------------------------------------|-------------------------------------|--------|-------------------------------------|-----------------|--|-------------------------|-----------------|--|------------|----------------|--|------------|------------------|--|------------|------------------------------------------|--|------------|------------------------------------------|----|--------------------------------------|----------------|--|-------------------------|-----------------|--|------------|----------------|--|------------|------------------|--|------------|-------------------------------------------|--|------------|-------------------------------------------|
| rev 0.0 | 06/23/00 | Initial Version. | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| rev 0.1 | 02/23/01 | <div>1. Added Sony Part Numbers for each device.</div> <div>2. Removed Asynchronous Output Enable (\overline{G}) support. Pin 6D now defined as “MCL”.</div> <div>3. Modified DC Recommended Operating Conditions section (p. 10).<table><tr><td>$V_{MIH-1.8}$ (min)</td><td>1.2V to 1.3V</td></tr><tr><td>$V_{MIH-1.5}$ (min)</td><td>1.2V to 1.1V</td></tr><tr><td>$V_{MIL-1.8}$ (max)</td><td>0.3V to 0.5V</td></tr><tr><td>$V_{MIL-1.5}$ (max)</td><td>0.3V to 0.4V</td></tr></table></div> <div>3. Modified DC Electrical Characteristics section (p. 11).<div>Added Average Power Supply Operating Current specifications at 250 MHz (I_{DD-4}).</div><div>Added Power Supply Deselect Operating Current specification at 250 MHz (I_{DD2-4}).</div></div> <div>4. Modified AC Electrical Characteristics section (p. 12).<div>Removed “-5” bin. Added “-44” bin.</div><table><tr><td>All Bins</td><td>Removed t_{KLCL} specifications</td><td></td></tr><tr><td>-33</td><td>t_{AVKH}, t_{BVKH}, t_{DVKH}</td><td>0.4ns to 0.7ns</td></tr><tr><td></td><td>t_{KHQV}, t_{KHQZ}</td><td>1.85ns to 1.8ns</td></tr><tr><td></td><td>t_{KHCH}, t_{KHCZ}</td><td>1.65ns to 1.7ns</td></tr><tr><td></td><td>t_{CHQV}</td><td>0.2ns to 0.4ns</td></tr><tr><td></td><td>t_{CHQX}</td><td>-0.2ns to -0.4ns</td></tr><tr><td></td><td>t_{CHCL}</td><td>$t_{KHKL} \pm 0.1$ to $t_{KHKL} \pm 0.2$</td></tr><tr><td></td><td>t_{CLCH}</td><td>$t_{KLKH} \pm 0.1$ to $t_{KLKH} \pm 0.2$</td></tr><tr><td>-4</td><td>t_{AVKH}, t_{BVKH}, t_{DVKH}</td><td>0.5ns to 0.8ns</td></tr><tr><td></td><td>t_{KHQV}, t_{KHQZ}</td><td>2.25ns to 2.1ns</td></tr><tr><td></td><td>t_{CHQV}</td><td>0.2ns to 0.5ns</td></tr><tr><td></td><td>t_{CHQX}</td><td>-0.2ns to -0.5ns</td></tr><tr><td></td><td>t_{CHCL}</td><td>$t_{KHKL} \pm 0.1$ to $t_{KHKL} \pm 0.25$</td></tr><tr><td></td><td>t_{CLCH}</td><td>$t_{KLKH} \pm 0.1$ to $t_{KLKH} \pm 0.25$</td></tr></table></div> <div>5. Updated the size and content of the Boundary Scan Registers (p. 21).</div> | $V_{MIH-1.8}$ (min) | 1.2V to 1.3V | $V_{MIH-1.5}$ (min) | 1.2V to 1.1V | $V_{MIL-1.8}$ (max) | 0.3V to 0.5V | $V_{MIL-1.5}$ (max) | 0.3V to 0.4V | All Bins | Removed t_{KLCL} specifications | | -33 | t_{AVKH} , t_{BVKH} , t_{DVKH} | 0.4ns to 0.7ns | | t_{KHQV} , t_{KHQZ} | 1.85ns to 1.8ns | | t_{KHCH} , t_{KHCZ} | 1.65ns to 1.7ns | | t_{CHQV} | 0.2ns to 0.4ns | | t_{CHQX} | -0.2ns to -0.4ns | | t_{CHCL} | $t_{KHKL} \pm 0.1$ to $t_{KHKL} \pm 0.2$ | | t_{CLCH} | $t_{KLKH} \pm 0.1$ to $t_{KLKH} \pm 0.2$ | -4 | t_{AVKH} , t_{BVKH} , t_{DVKH} | 0.5ns to 0.8ns | | t_{KHQV} , t_{KHQZ} | 2.25ns to 2.1ns | | t_{CHQV} | 0.2ns to 0.5ns | | t_{CHQX} | -0.2ns to -0.5ns | | t_{CHCL} | $t_{KHKL} \pm 0.1$ to $t_{KHKL} \pm 0.25$ | | t_{CLCH} | $t_{KLKH} \pm 0.1$ to $t_{KLKH} \pm 0.25$ |
| $V_{MIH-1.8}$ (min) | 1.2V to 1.3V | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| $V_{MIH-1.5}$ (min) | 1.2V to 1.1V | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| $V_{MIL-1.8}$ (max) | 0.3V to 0.5V | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| $V_{MIL-1.5}$ (max) | 0.3V to 0.4V | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| All Bins | Removed t_{KLCL} specifications | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| -33 | t_{AVKH} , t_{BVKH} , t_{DVKH} | 0.4ns to 0.7ns | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| | t_{KHQV} , t_{KHQZ} | 1.85ns to 1.8ns | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| | t_{KHCH} , t_{KHCZ} | 1.65ns to 1.7ns | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| | t_{CHQV} | 0.2ns to 0.4ns | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| | t_{CHQX} | -0.2ns to -0.4ns | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| | t_{CHCL} | $t_{KHKL} \pm 0.1$ to $t_{KHKL} \pm 0.2$ | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| | t_{CLCH} | $t_{KLKH} \pm 0.1$ to $t_{KLKH} \pm 0.2$ | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| -4 | t_{AVKH} , t_{BVKH} , t_{DVKH} | 0.5ns to 0.8ns | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| | t_{KHQV} , t_{KHQZ} | 2.25ns to 2.1ns | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| | t_{CHQV} | 0.2ns to 0.5ns | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| | t_{CHQX} | -0.2ns to -0.5ns | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| | t_{CHCL} | $t_{KHKL} \pm 0.1$ to $t_{KHKL} \pm 0.25$ | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| | t_{CLCH} | $t_{KLKH} \pm 0.1$ to $t_{KLKH} \pm 0.25$ | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| rev 0.2 | 07/06/01 | <div>1. Modified DC Electrical Characteristics section (p. 11).<div>Added I_{DD-33} and I_{DD-44} Average Power Supply Operating Current specifications.</div></div> <div>2. Added 209 Pin BGA Package Dimensions (p. 26).</div> | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| rev 0.3 | 02/22/02 | <div>1. Added BGA Package Thermal Characteristics (p. 10).</div> <div>2. Modified AC Electrical Characteristics section (p. 13).<div>Removed “-44” bin. Added “-5” bin.</div><table><tr><td>-4</td><td>t_{CHCL}</td><td>$t_{KHKL} \pm 0.25$ to $t_{KHKL} \pm 0.2$</td></tr><tr><td></td><td>t_{CLCH}</td><td>$t_{KLKH} \pm 0.25$ to $t_{KLKH} \pm 0.2$</td></tr></table></div> <div>3. Added JTAG ID Codes (p. 23).</div> <div>4. Added JTAG Boundary Scan Register Bit Order Assignments (pp. 24-26).</div> | -4 | t_{CHCL} | $t_{KHKL} \pm 0.25$ to $t_{KHKL} \pm 0.2$ | | t_{CLCH} | $t_{KLKH} \pm 0.25$ to $t_{KLKH} \pm 0.2$ | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| -4 | t_{CHCL} | $t_{KHKL} \pm 0.25$ to $t_{KHKL} \pm 0.2$ | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| | t_{CLCH} | $t_{KLKH} \pm 0.25$ to $t_{KLKH} \pm 0.2$ | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| rev 1.0 | 07/19/02 | <div>1. Modified Pin Assignment section (p. 2-4).<table><tr><td>Byte Write Enable Control Inputs</td><td>\overline{BWx} to \overline{Bx}</td></tr><tr><td>Pin 1K</td><td>\overline{CQ} to $\overline{CQ2}$</td></tr><tr><td>Pin 2K</td><td>\overline{CQ} to $\overline{CQ2}$</td></tr><tr><td>Pin 10K</td><td>\overline{CQ} to $\overline{CQ1}$</td></tr><tr><td>Pin 11K</td><td>\overline{CQ} to $\overline{CQ1}$</td></tr><tr><td>Pin 6J</td><td>\overline{CQ} to $\overline{CQ1}$</td></tr><tr><td>Pin 6L</td><td>\overline{CQ} to $\overline{CQ1}$</td></tr><tr><td>Pin 6M</td><td>\overline{CQ} to $\overline{CQ1}$</td></tr></table></div> | Byte Write Enable Control Inputs | \overline{BWx} to \overline{Bx} | Pin 1K | \overline{CQ} to $\overline{CQ2}$ | Pin 2K | \overline{CQ} to $\overline{CQ2}$ | Pin 10K | \overline{CQ} to $\overline{CQ1}$ | Pin 11K | \overline{CQ} to $\overline{CQ1}$ | Pin 6J | \overline{CQ} to $\overline{CQ1}$ | Pin 6L | \overline{CQ} to $\overline{CQ1}$ | Pin 6M | \overline{CQ} to $\overline{CQ1}$ | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| Byte Write Enable Control Inputs | \overline{BWx} to \overline{Bx} | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| Pin 1K | \overline{CQ} to $\overline{CQ2}$ | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| Pin 2K | \overline{CQ} to $\overline{CQ2}$ | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| Pin 10K | \overline{CQ} to $\overline{CQ1}$ | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| Pin 11K | \overline{CQ} to $\overline{CQ1}$ | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| Pin 6J | \overline{CQ} to $\overline{CQ1}$ | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| Pin 6L | \overline{CQ} to $\overline{CQ1}$ | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| Pin 6M | \overline{CQ} to $\overline{CQ1}$ | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |

| Rev. # | Rev. Date | Description of Modifications |
|--------|-----------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| | | <p>2. Modified I/O Capacitance section (p. 10).</p> <p>C_{KIN} 3.5pF to 4.0pF</p> <p>3. Modified DC Recommended Operating Conditions section (p. 11).</p> <p>Combined -1.8 and -1.5 line items into one for V_{DDQ}, V_{IH}, V_{IL}, V_{MIH}, and V_{MIL}.</p> <p>V_{IH} (min) 1.0V to $V_{DDQ}/2 + 0.3V$</p> <p>V_{IL} (max) 0.6V to $V_{DDQ}/2 - 0.3V$</p> <p>V_{MIH} (min) 1.1V to $V_{DDQ}/2 + 0.4V$</p> <p>V_{MIL} (max) 0.5V to $V_{DDQ}/2 - 0.4V$</p> <p>Removed notes 1 and 2.</p> <p>4. Modified DC Electrical Characteristics section (p. 12).</p> <p>Added MCH and MCL Input Leakage Current specifications.</p> <p>Reduced x72 Average Power Supply Operating Currents by 100mA.</p> <p>Reduced x36 Average Power Supply Operating Currents by 50mA.</p> <p>Reduced x18 Average Power Supply Operating Currents by 20mA.</p> <p>5. Modified AC Electrical Characteristics section (p. 13).</p> <p>-33 t_{KHCH} (max), t_{KHCZ} 1.7ns to 1.8ns</p> <p>-4 t_{KHCH} (max), t_{KHCZ} 2.0ns to 2.1ns</p> <p>-5 t_{KHCH} (max), t_{KHCZ} 2.2ns to 2.3ns</p> <p>6. Modified JTAG DC Recommended Operating Conditions section (p. 19).</p> <p>V_{TIH} (min) 1.2V to $V_{DD}/2 + 0.3V$</p> <p>V_{TIL} (max) 0.6V to $V_{DD}/2 - 0.3V$</p> <p>I_{TLI} (min) -10uA to -20uA</p> <p>7. Modified JTAG AC Electrical Characteristics section (p. 20).</p> <p>t_{THTH} 20ns to 50ns</p> <p>t_{THTL}, t_{TLTH} 8ns to 20ns</p> <p>Added t_{CS} Capture Setup and t_{CH} Capture Hold specifications.</p> <p>8. Modified TAP Registers section (p. 22).</p> <p>Instruction Register Codes 011, 110 Bypass to Private</p> <p>9. Modified Boundary Scan Register Bit Order Assignments section (p. 24-25).</p> <p>x72 Bit 47 10A to 11A</p> <p>x72 Bit 48 11A to 10A</p> <p>x36 Bit 29 10A to 11A</p> <p>x36 Bit 30 11A to 10A</p> |